

BGA824N6

High-Gain Low Noise Ampifier for Global Navigation Satellite Systems (GNSS) with Temparature Variation

Application Note AN325

Revision: Rev.1.1 2018-02-09

RF and **Protection Devices**

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11	Updated LTE B13 second harmonic to be LNA output referred value (B13 OHD2)									

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1 Introduction of Global Navigation Satellite Systems (GNSS)

The BGA824N6 is a front-end Low Noise Amplifier (LNA) for Global Navigation Satellite Systems (GNSS) application. It is based on Infineon Technologies' B7HF Silicon-Germanium (SiGe) technology, enabling a cost-effective solution in a TSNP-6-2 leadless package with ultra low noise figure, high gain, high linearity and low current consumption over a wide range of supply voltages from 3.6 V down to 1.5 V. All these features make BGA824N6 an excellent choice for GNSS LNA as it improves sensitivity, provide greater immunity against out-of-band jammer signals, reduces filtering requirement and hence the overall cost of the GNSS receiver.

The GNSS satellites are at an orbit altitude of more than 20,000 km away from earth's surface and transmit power in the range of +47 dBm. After taking losses (atmospheric, antenna etc.) into account, the received signal strength at the GNSS device input is very low in the range of -130 dBm. The ability of the GNSS device to receive such low signal strength and provide meaningful information to the end-user depends strongly on the noise figure of the GNSS receives chain. This ability which is called receiver sensitivity can be improved by using a low-noise amplifier with low noise figure and high gain at the input of the receiver chain. The improved sensitivity results in a shorter Time-To-First-Fix (TTFF), which is the time required for a GNSS receiver to acquire satellite signals and navigation data, and calculate a position. Noise figure of the LNA defines the overall noise figure as low as 0.55 dB and high gain of 17 dB, thereby improving the receiver sensitivity significantly.

The ever growing demand to integrate more and more functionality into one device leads to many challenges when transmitter/receiver has to work simultaneously without degrading the performance of each other. In today's smart-phones a GNSS receiver simultaneously coexists with transceivers in the GSM/EDGE/UMTS/LTE bands. These 3G/4G transceivers transmit high power in the range of +24 dBm which due to insufficient isolation couple to the GNSS receiver. The cellular signals can mix to produce Intermodulation products exactly in the GNSS receiver frequency band. For example, GSM 1712.7 MHz mixes with UMTS 1850 MHz to produce third-order-product exactly at GPS. To quantify the effect, BGA824N6 shows out-of-band input IP3 at GPS of +7 dBm as a result of frequency mixing between GSM



1712.7 MHz and UMTS 1850 MHz with power levels of -20 dBm. BGA824N6 has a high outof-band input 3rd order intercept point (IIP3) of +7 dBm, so that it is especially suitable for the GPS function in mobile phones.

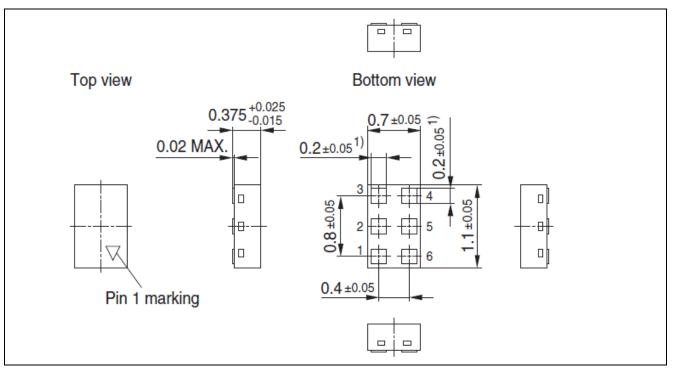


Figure 1 BGA824N6 TSNP-6-2 leadless Package size

As the industry inclines toward assembly miniaturization and also surface mount technology matures, there is a desire to have smaller and thinner components. This is especially the case with portable electronics where higher circuit density allows device design flexibility and also optimum use of the limited space available. BGA824N6 has a small package with dimensions of 0.70mm x 1.1mm x 0.375mm and it requires only two components at its input, the capacitor at the input has to be used if a DC block is required and the inductor provides input matching. The DC block at input is optional as it is usually provided by the pre-filter before the LNA in many GPS applications. All the device manufacturers implement very good power supply filtering on their boards so that the RF bypass capacitor mentioned in this application circuit may not be needed in the end. The minimal number of external SMD components reduces the application bill of materials and the PCB area thus making it an ideal solution for compact and cost-effective GNSS LNA. The output of the BGA824N6 is internally matched to 50 Ω , and a DC blocking capacitor is integrated on-chip, thus no external component is required at the output.



BGA824N6 High-Gain LNA for GPS/GLONASS/Galileo/COMPASS Introduction of Global Navigation Satellite Systems (GNSS)

The device also integrates an on-chip ESD protection which can resist until 2 kV (referenced to Human Body Model). The integrated power on/off feature provides for low power consumption and increased stand-by time for GNSS handsets. Moreover, the low current consumption (3.8 mA) makes the device suitable for portable technology like GNSS receivers and mobiles phones.

The Internal circuit diagram of the BGA824N6 is presented in Figure 3. Table 1 show the pin assignment of BGA824N6. Table 2 shows the truth table to turn on/off BGA824N6 by applying different voltage to the PON pin.



2 BGA824N6 Overview

2.1 Features

- High insertion power gain: 17.0 dB
- Out-of-band input 3rd order intercept point: +7 dBm
- Input 1 dB compression point: -6 dBm
- Low noise figure: 0.55 dB
- Low current consumption: 3.8 mA
- Operating frequencies: 1550 1615 MHz
- Supply voltage: 1.5 V to 3.6 V
- Digital on/off switch (1V logic high level)
- Ultra small TSNP-6-2 leadless package (footprint: 0.7 x 1.1 mm2)
- B7HF Silicon Germanium technology
- RF output internally matched to 50 Ω
- Only 1 external SMD component necessary
- 2kV HBM ESD protection (including AI-pin)
- Pb-free (RoHS compliant) package



Figure 2 BGA824N6 in TSNP-6-2



2.2 Key Applications of BGA824N6

- Ideal for all Global Navigation Satellite Systems (GNSS) like
 - GPS (Global Positioning System) working in the L1 band at 1575.42 MHz
 - GLONASS (Russian GNSS) working in the L1 band from 1598.06 MHz to 1605.38 MHz
 - Galileo (European GNSS) working in the E2-L1-E1 band from 1559 MHz to 1592 MHz
 - COMPASS (Chinese Beidou Navigation System) working in E2 band at 1561.10 MHz and E1 band at 1589.74 MHz

2.3 Description

The BGA824N6 is a front-end low noise amplifier for Global Navigation Satellite Systems (GNSS) from 1550 MHz to 1615 MHz like GPS, GLONASS, Beidou, Galileo and others. The LNA provides 17.0 dB gain and 0.55 dB noise figure at a current consumption of 3.8 mA in the application configuration described in **Chapter 3**. The BGA824N6 is based upon Infineon Technologies'B7HF Silicon Germanium technology. It operates from 1.5 V to 3.6 V supply voltage.



BGA824N6 Overview

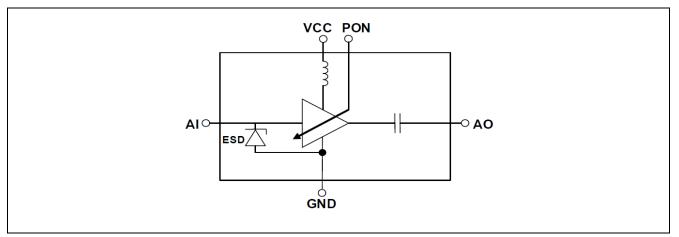


Figure 3 Equivalent Circuit of BGA824N6

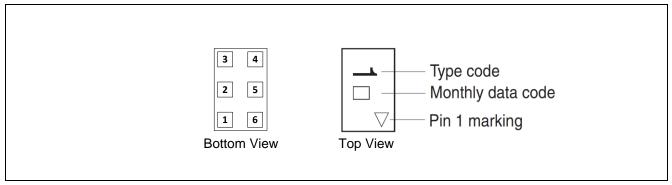


Figure 4 Package and pin connections of BGA824N6

Table 1Pin Assignment of BGA824N6

Pin No.	Symbol	Function
1	GND	Ground
2	VCC	DC supply
3	AO	LNA output
4	GND	Ground
5	AI	LNA input
6	PON	Power on control

Table 2 Pin Assignment of BGA824N6

LNA	l pin		
Mode		Min	Мах
ON	PON, on	1.0 V	VCC
OFF	PON, off	0 V	0.4 V



...

3 Application Circuit and Performance Overview

Device:BGA824N6Application:High-Gain Low Noise Ampifier for Global Navigation Satellite
Systems (GNSS) with Temparature VariationPCB Marking:BGA824N6

3.1 Summary of Measurement Results

Table 3 Electrical Characteristics for COMPASS/Galileo at Vcc = Vpon = 2.8 V

Parameter	Symbol			Value	Unit	Comment/Test Condition		
Frequency Range	Freq			1559-159	MHz			
DC Voltage	Vcc			2.8			V	
Temparature	Т	-40	-15	0	25	85	°C	
DC Current	lcc	4.1	4.1	4	3.9	3.7	mA	
Gain	G	18	17.7	17.5	17.2	16.2	dB	
Noise Figure	NF	0.4	0.47	0.52	0.62	0.9	dB	PCB and SMA losses 0.07 dB are substracted
Input Return Loss	RLin	14.5	14.2	14	13.6	12	dB	
Output Return Loss	RLout	26.4	25.1	24.3	23.6	23	dB	
Reverse Isolation	IRev	23.1	23.1	23.2	23.2	23.2	dB	
Input P1dB	IP1dB	-7.3	-7.2	-7.2	-7.2	-7.1	dBm	f _{galileo} = 1559 MHz
Input IP3 In-band	IIP3	3.3	3	2.7	1.6	0.1	dBm	$f_{1gal} = 1559 \text{ MHz}$ $f_{2gal} = 1560 \text{MHz}$ Input power= -30dBm
Stability	k	>1						Unconditionnally Stable from 0 to 10GHz



BGA824N6 High-Gain LNA for GPS/GLONASS/Galileo/COMPASS Application Circuit and Performance Overview

Parameter	Symbol			Value	Unit	Comment/Test Condition		
Frequency Range	Freq			1575.42			MHz	
DC Voltage	Vcc			2.8			V	DC Voltage
Temparature	Т	-40	-15	0	25	85	°C	
DC Current	lcc	4.1	4.1	4	3.9	3.7	mA	
Gain	G	17.9	17.6	17.4	17	16	dB	
Noise Figure	NF	0.43	0.5	0.55	0.64	0.91	dB	PCB and SMA losses 0.07 dB are substracted
Input Return Loss	RLin	15.5	15.1	14.9	14.5	12.7	dB	
Output Return Loss	RLout	21.8	21.1	20.5	20	19.7	dB	
Reverse Isolation	IRev	23	23.1	23.1	23.2	23.2	dB	
Input P1dB	IP1dB	-7.2	-7.1	-7.1	-7.1	-7	dBm	f _{galileo} = 1575.42 MHz
Input IP3 In-band	IIP3	3.7	3.4	3.1	2	0.5	dBm	$f_{1gps} = 1575 \text{ MHz}$ $f_{2gps} = 1576 \text{MHz}$ Input power= -30dBm
Out-of-band IP3 (input referred)	OoB IIP3	11.3	10.7	10.1	8.2	5.9	dBm	f ₁ = 1712.7 MHz f ₂ = 1850 MHz Input power = -20dBm f _{IIP3} = 1575.4 MHz
LTE band-13 2 nd Harmonic (output referred(B13 OHD2				-28.2		dBm	f _{IN} = 787.76 MHz P _{IN} = -25 dBm f _{H2} = 1575.52 MHz
Stability	k			>1		Unconditionnally Stable from 0 to 10GHz		



BGA824N6 High-Gain LNA for GPS/GLONASS/Galileo/COMPASS Application Circuit and Performance Overview

Table 5Electrical Characteristics for GLONASS at Vcc = Vpon = 2.8 V									
Parameter	Symbol			Value	Unit	Comment/Test Condition			
Frequency Range	Freq			1598-160	6		MHz		
DC Voltage	Vcc			2.8			V		
Temparature	Т	-40	-15	0	25	85	°C		
DC Current	lcc	4.1	4.1	4	3.9	3.7	mA		
Gain	G	17.7	17.4	17.2	16.9	15.9	dB		
Noise Figure	NF	0.42	0.51	0.55	0.68	0.93	dB	PCB and SMA losses 0.07 dB are substracted	
Input Return Loss	RLin	16.9	16.5	16.3	15.9	13.9	dB		
Output Return Loss	RLout	17.1	16.7	16.3	16	15.7	dB		
Reverse Isolation	IRev	-23	-23.1	-23.1	-23.1	-23.2	dB		
Input P1dB	IP1dB	-6.9	-6.8	-6.8	-6.7	-6.4	dBm	$F_{GLONASS} = 1605.38 \text{ MHz}$	
Output P1dB	OP1dB	10.8	10.6	10.4	10.2	9.5	dBm		
Input IP3 In-band	IIP3	4	3.7	3.3	2.4	0.9	dBm		
Output IP3 In-band	OIP3	21.7	21.1	20.5	19.3	16.8	dBm	$f_{GLONASS} = 1602 \text{ MHz}$ $f_{GLONASS} = 1603 \text{MHz}$ Input power= -30dBm	
Stability	k		>1					Unconditionnally Stable from 0 to 10GHz	



Application Circuit and Performance Overview

3.2 Summary BGA824N6 as 1550-1615 MHz LNA for GNSS

This application note presents the high gain low noise amplifier for Global Navigation Satellite Systems (GNSS) using BGA824N6.

The circuit requires only one 0402 passive component. It has in band gain of 17dB. The gain flatness over the whole temperature range (-40°C to 85°C) is less than 2dB. The circuit achieves input return loss better than 12dB and output return loss more than 15.7 dB for the whole temperature range. In room temperature noise figure is 0.55dB (SMA and PCB losses are subtracted) and it increases to 0.93dB for 85°C. Furthermore, the circuit is unconditionally stable till 10 GHz.

At 1575 MHz, using two tones spacing of 1 MHz, the output third order intercept point OIP3 reaches 19 dBm. OIP3 varies form 16.5 dBm to 21.6 dBm for the whole frequency range. Input P1dB of the GNSS LNA is about -7dBm and it is almost constant over the whole temaprature range. The out of band OIP3 reaches 8.2 dBm at room temperature at 1575.4 MHz frequency. And this circuit shows very good H2 performance -28.2 dBm for GPS frequency.



Application Circuit and Performance Overview

3.3 Schematics and Bill-of-Materials

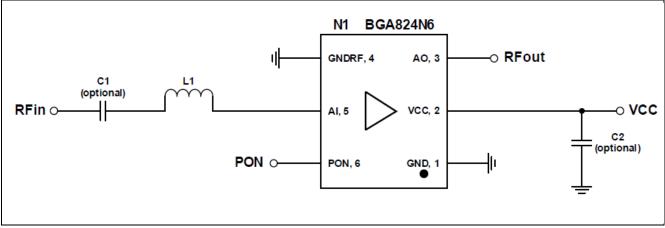
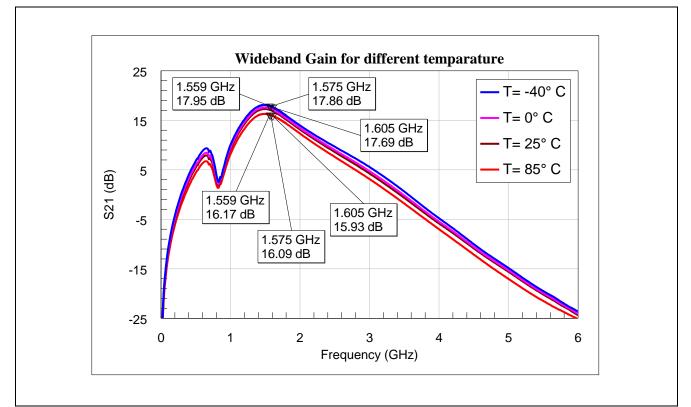


Figure 5 Schematics of the BGA824N6 Application Circuit

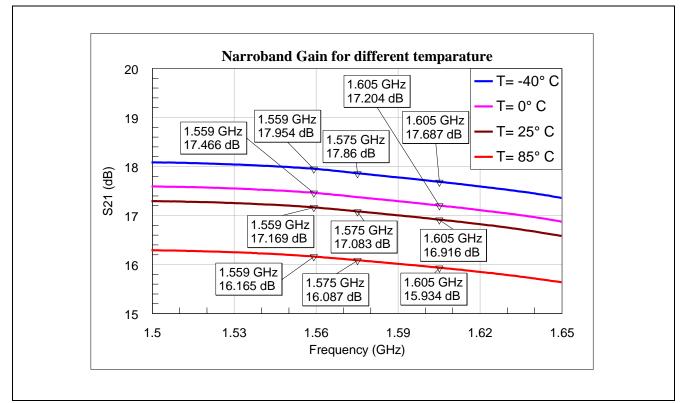
Table 6Bill-of-Materials

Symbol	Value	Unit	Size	Manufacturer	Comment
C2 (optional)	1	nF	0402	Various	DC block
C2 (optional)	>10	nF	0402	Various	RF bypass
L1	6.8	nH	0402	Murata LQW type	Input matching
N1	BGA824N6		TSNP-6-2	Infineon	SiGe LNA













Measurement Graphs

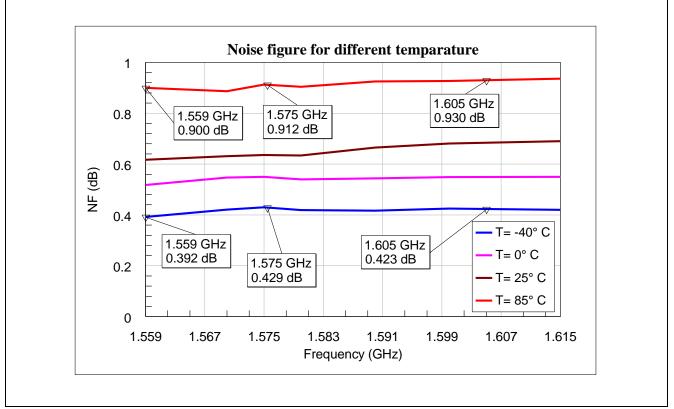


Figure 8 Noise figure of BGA824N6 for COMPASS, Galileo, GPS and GLONASS bands

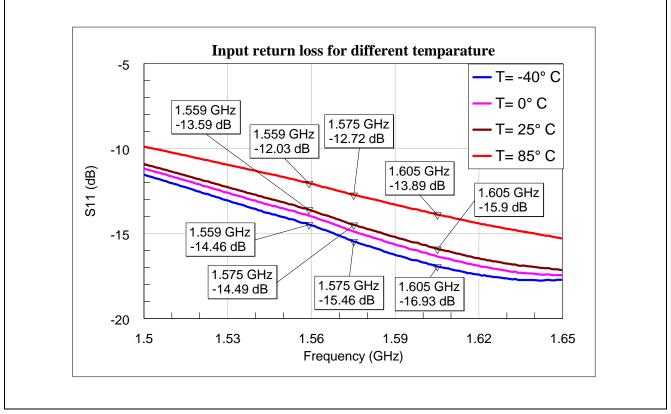


Figure 9 Input matching of BGA824N6 for COMPASS, Galileo, GPS and GLONASS bands



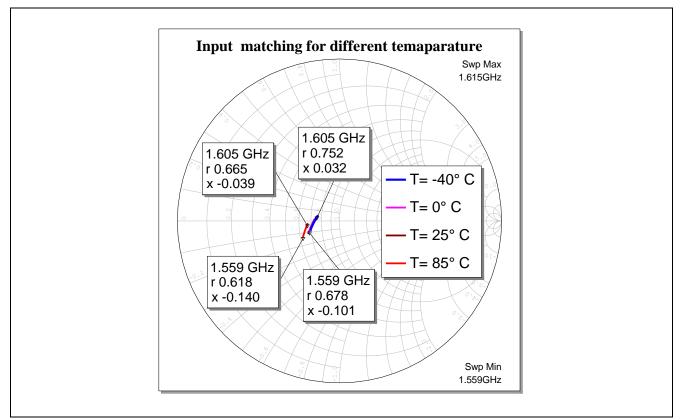


Figure 10 Input matching smith chart for COMPASS, Galileo, GPS and GLONASS bands

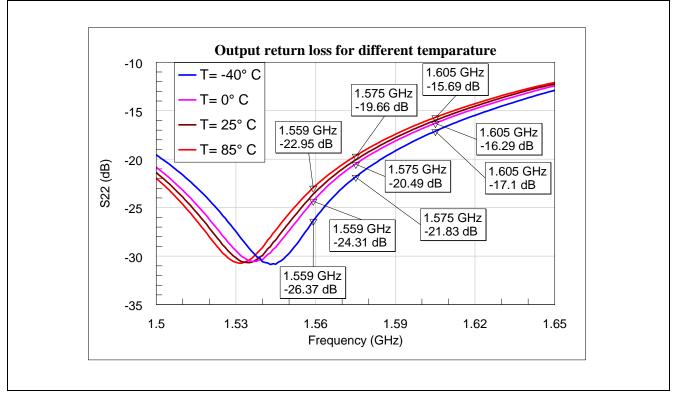


Figure 11 Output matching of BGA824N6 for COMPASS, Galileo, GPS and GLONASS bands



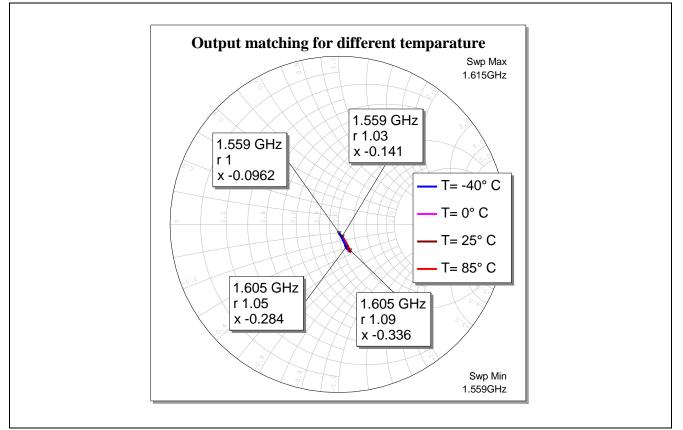


Figure 12 Output matching smith chart for COMPASS, Galileo, GPS and GLONASS bands

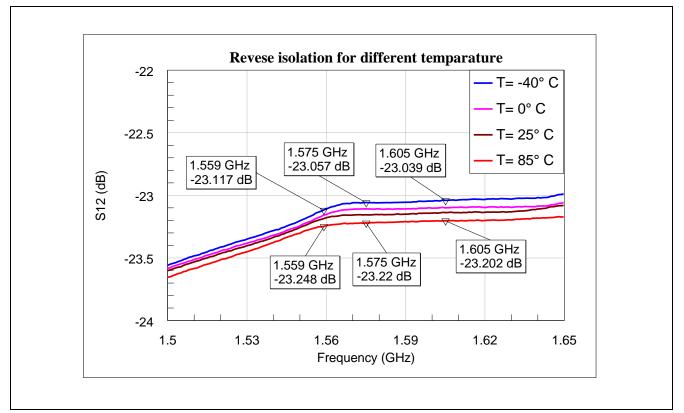


Figure 13 Reverse isolation of BGA824N6 for COMPASS, Galileo, GPS and GLONASS bands



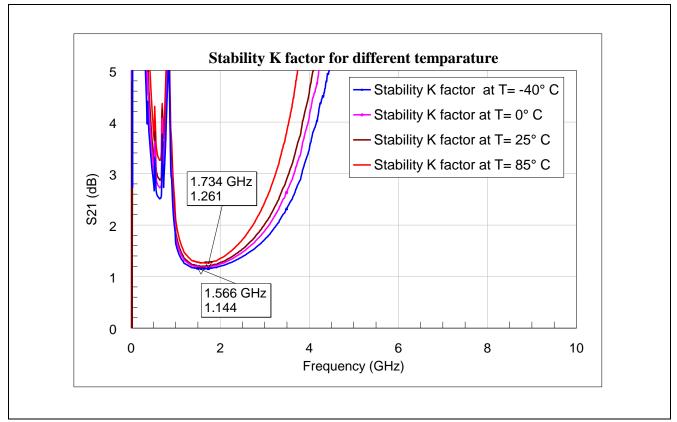


Figure 14 Stability factor k of BGA824N6 upto 10GHz

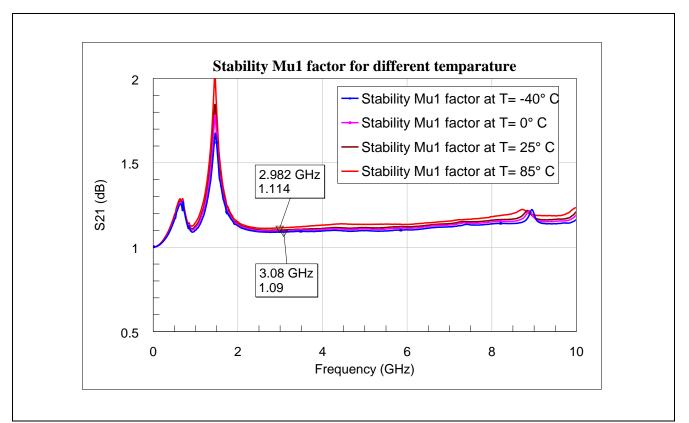


Figure 15 Stability factor µ1 of BGA824N6 upto 10GHz





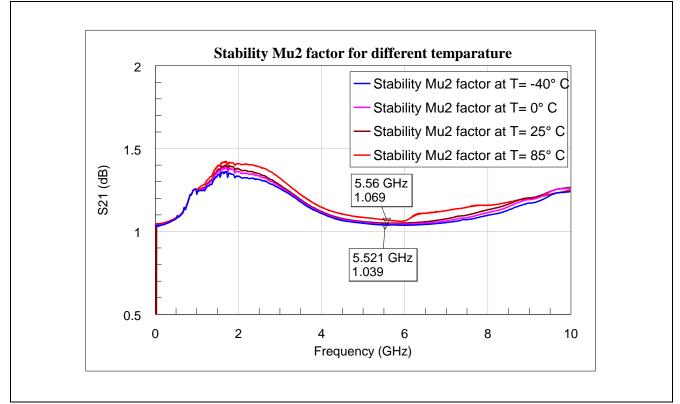


Figure 16 Stability factor µ2 of BGA824N6 upto 10GHz

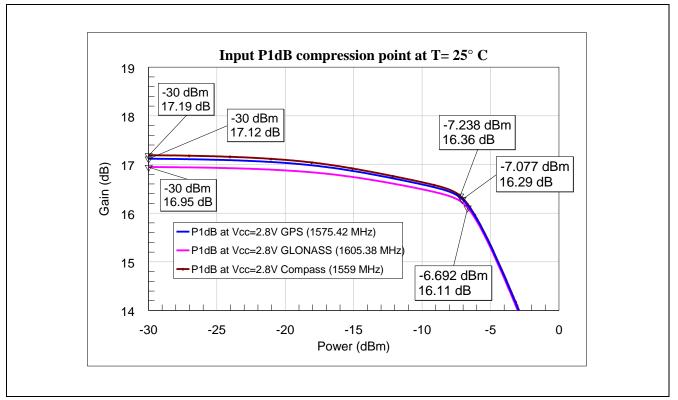


Figure 17 Input 1 dB compression point of BGA824N6 at supply voltage of 2.8V for COMPASS, Galileo, GPS and GLONASS bands



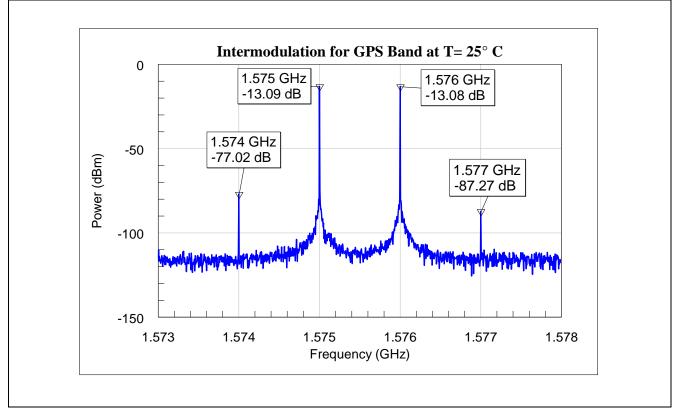


Figure 18 Carrier and intermodulation products of BGA824N6 for GPS band

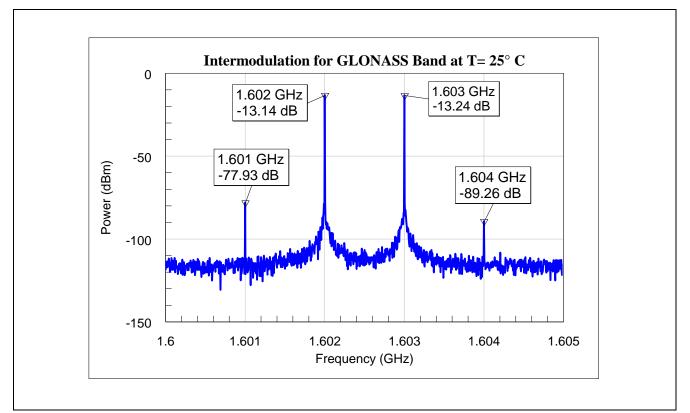


Figure 19 Carrier and intermodulation products of BGA824N6 for GLONASS band



Evaluation Board and Layout Information

Evaluation Board and Layout Information 5

In this application note, the following PCB is used: PCB Marking: BGAx24N6 PCB material: FR4 εr of PCB material: 4.3

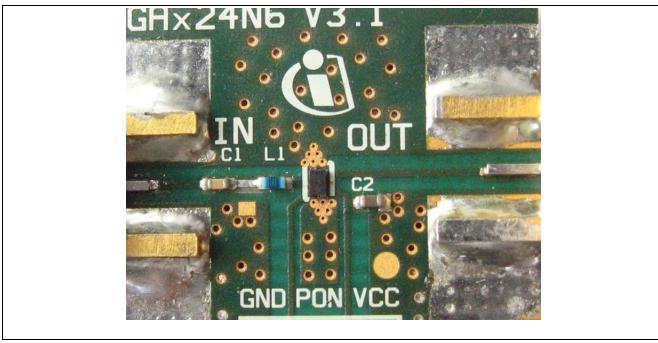


Figure 20 Picture of Evaluation Board (overview)

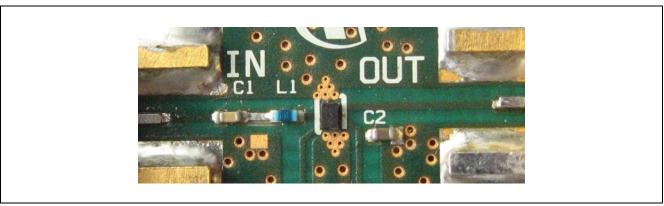


Figure 21 Picture of Evaluation Board (detailed view)



BGA824N6 High-Gain LNA for GPS/GLONASS/Galileo/COMPASS Evaluation Board and Layout Information

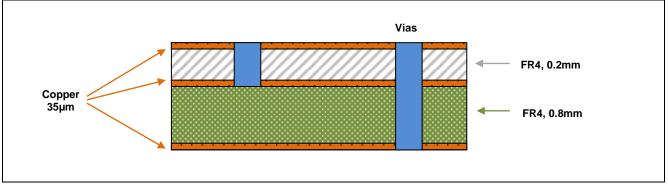


Figure 22 PCB Layer Information



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